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# RD74LVC16373B

# 16-bit D-type Transparent Latches with 3-state Outputs

REJ03D0500-0100 Rev.1.00 Jan. 24, 2005

#### Description

The RD74LVC16373B has sixteen D type latches with three state outputs in a 48 pin package. When the latch enable input is high, the Q outputs will follow the D inputs. When the latch enable goes low, data at the D inputs will be retained at the outputs until latch enable returns high again. When a high logic level is applied to the output control input  $(1\overline{G}, 2\overline{G})$ , all outputs go to a high impedance state, regardless of what signals are present at the other inputs and the state of the storage elements. Low voltage and high-speed operation is suitable at the battery drive product (note type personal computer) and low power consumption extends the life of a battery for long time operation.

## Features

- $V_{CC} = 1.65 \text{ V}$  to 5.5 V
- All inputs  $V_{IH}$  (Max.) = 5.5 V (@V<sub>CC</sub> = 0 V to 5.5 V)
- All outputs  $V_{OUT}$  (Max.) = 5.5 V (@V<sub>CC</sub> = 0 V or output off state)
- Typical V<sub>OL</sub> ground bounce < 0.8 V (@V<sub>CC</sub> = 3.3 V, Ta = 25°C)
- Typical  $V_{OH}$  undershoot > 2.0 V (@V<sub>CC</sub> = 3.3 V, Ta = 25°C)
- High output current  $\pm 4 \text{ mA} (@V_{CC} = 1.65 \text{ V})$ 
  - $\pm 8 \text{ mA} (@V_{CC} = 2.3 \text{ V})$  $\pm 12 \text{ mA} (@V_{CC} = 2.7 \text{ V})$  $\pm 24 \text{ mA} (@V_{CC} = 3.0 \text{ V to } 5.5 \text{ V})$
- Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
RD74LVC16373BTEL	TSSOP-48 pin	PTSP0048KA–A (TTP–48DBV)	Т	EL (1,000 pcs/reel)

## **Function Table**

	Inputs		
G	LE	D	Output Q
Н	Х	Х	Z
L	Н	L	L
L	Н	Н	Н
L	L	Х	Q <sub>0</sub>

H: High level

L: Low level

X: Immaterial

Z: High impedance

Q<sub>0</sub>: Level of Q before the indicated steady input conditions were established.



## **Pin Arrangement**

Γ		
1 <u><u>G</u> 1</u>		48 1LE
1Q1 2		47 1D1
1Q2 <u>3</u>	G D	46 1D2
GND 4		45 GND
1Q3 5	G D	44 1D3
1Q4 <u>6</u> —	G D	43 1D4
V <sub>CC</sub> 7		42 V <sub>CC</sub>
1Q5 <u>8</u>	G D	41 1D5
1Q6 9—	G D	40 1D6
GND 10	G D	39 GND
1Q7 11		38 1D7
1Q812		37 1D8
2Q1 13-		36] 2D1
2Q2 14	G Q D	35 2D2
GND 15	G	34 GND
2Q316		33 2D3
2Q4 17		32 2D4
Vcc 18		31 V <sub>CC</sub>
2Q5 19-	G D	30 2D5
2Q6 20—	G D	29 2D6
GND 21		28 GND
2Q7 22_		27 2D7
2Q8 23_	G Q D	26 2D8
2 <u>G</u> 24		25 2LE
	(Top view)	



## **Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V <sub>CC</sub>	-0.5 to 7.0	V	
Input diode current	l <sub>ik</sub>	-50	mA	V <sub>I</sub> = -0.5 V
Input voltage	VI	-0.5 to 7.0	V	
Output diode current	Ι <sub>ΟΚ</sub>	-50	mA	V <sub>O</sub> = -0.5 V
		50		$V_{\rm O} = V_{\rm CC} + 0.5 \ V$
Output voltage	Vo	–0.5 to V <sub>CC</sub> +0.5	V	Output "H" or "L"
		-0.5 to 7.0		Output "Z" or V <sub>CC</sub> : OFF
Output current	lo	±50	mA	
V <sub>CC</sub> , GND current / pin	I <sub>CC</sub> or I <sub>GND</sub>	100	mA	
Storage temperature	Tstg	-65 to +150	°C	

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

### **Recommended Operating Conditions**

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V <sub>cc</sub>	1.5 to 5.5	V	Data hold
		1.65 to 5.5		At operation
Input/output voltage	VI	0 to 5.5	V	G, LE, D
	Vo	0 to V <sub>CC</sub>		Output "H" or "L"
		0 to 5.5		Output "Z" or V <sub>CC</sub> : OFF
Operating temperature	Та	-40 to 85	°C	
Output current	I <sub>ОН</sub>	-4	mA	V <sub>CC</sub> = 1.65 V
		8		V <sub>CC</sub> = 2.3 V
		-12		$V_{CC} = 2.7 V$
		-24		V <sub>CC</sub> = 3.0 V to 5.5 V
	I <sub>OL</sub>	4	mA	V <sub>CC</sub> = 1.65 V
		8		$V_{CC} = 2.3 V$
		12		V <sub>CC</sub> = 2.7 V
		24		$V_{CC} = 3.0 \text{ V} \text{ to } 5.5 \text{ V}$
Input rise / fall time <sup>*1</sup>	t <sub>r</sub> , t <sub>f</sub>	20	ns/V	$V_{CC} = 1.65 \text{ V to } 2.7 \text{ V}$
		10		$V_{CC} = 3.0 \text{ V}$ to 5.5 V

Notes: 1. This item guarantees maximum limit when one input switches. Waveform: Refer to test circuit of switching characteristics.



# **Electrical Characteristics**

			Ta = -40	) to 85°C		
Item	Symbol	V <sub>cc</sub> (V)	Min	Max	Unit	Test Conditions
Input voltage	VIH	1.65 to 1.95	V <sub>CC</sub> ×0.65	_	V	
		2.3 to 2.7	1.7	_		
		2.7 to 3.6	2.0	—		
		4.5 to 5.5	V <sub>CC</sub> ×0.7	—		
	VIL	1.65 to 1.95	—	V <sub>CC</sub> ×0.35		
		2.3 to 2.7	—	0.7		
		2.7 to 3.6	—	0.8		
		4.5 to 5.5	—	V <sub>CC</sub> ×0.3		
Output voltage	V <sub>OH</sub>	1.65 to 5.5	V <sub>CC</sub> -0.2	—	V	I <sub>OH</sub> = -100 μA
		1.65	1.2	—		$I_{OH} = -4 \text{ mA}$
		2.3	1.7	—		$I_{OH} = -8 \text{ mA}$
		2.7	2.2	—		I <sub>OH</sub> = -12 mA
		3.0	2.4	—		
		3.0	2.2	—		I <sub>OH</sub> = -24 mA
		4.5	3.8	—		
	V <sub>OL</sub>	1.65 to 5.5	—	0.2		I <sub>OL</sub> = 100 μA
		1.65	—	0.45		$I_{OL} = 4 \text{ mA}$
		2.3	—	0.7		$I_{OL} = 8 \text{ mA}$
		2.7	—	0.4		I <sub>OL</sub> = 12 mA
		3.0	—	0.55		I <sub>OL</sub> = 24 mA
		4.5	—	0.55		
Input current	I <sub>IN</sub>	0 to 5.5	—	±5.0	μA	$V_{IN} = 5.5 V \text{ or GND}$
Output leak current	I <sub>OFF</sub>	0	—	±5.0	μA	$V_{IN} / V_{OUT} = 5.5 V$
Off state output	loz	2.7 to 5.5	—	±5.0	μA	$V_{IN} = V_{CC}$ or GND
current						$V_{OUT} = 5.5 V \text{ or GND}$
Quiescent supply	I <sub>CC</sub>	2.7 to 3.6		±10.0	μA	$V_{IN} = 3.6$ to 5.5 V
current		2.7 to 5.5		10.0	μA	$V_{IN} = V_{CC}$ or GND
	$\Delta I_{CC}$	2.7 to 3.6	_	500	μA	$V_{IN}$ = one input at (V <sub>CC</sub> -0.6)V, other inputs at V <sub>CC</sub> or GND



# **Switching Characteristics**

			Т	a = –40 to 85	5°C		From	То
ltem	Symbol	V <sub>cc</sub> (V)	Min	Тур	Max	Unit	(Input)	(Output)
Propagation delay time	t <sub>PLH</sub>	1.8±0.15	1.0	_	19.1	ns	D	Q
	t <sub>PHL</sub>	2.5±0.2	1.0	_	9.6			
		2.7	1.0	_	7.7			
		3.3±0.3	1.5	_	7.0			
		5.0±0.5	1.0	_	5.5			
	t <sub>PLH</sub>	1.8±0.15	1.0	_	19.1	ns	LE	Q
	t <sub>PHL</sub>	2.5±0.2	1.0	_	9.6			
		2.7	1.0	_	7.7			
		3.3±0.3	1.5	_	7.0			
		5.0±0.5	1.0	_	5.5			
Output enable time	t <sub>ZH</sub>	1.8±0.15	1.0	_	20.0	ns	G	Q
	t <sub>ZL</sub>	2.5±0.2	1.0	_	10.5			
		2.7	1.0	_	8.0			
		3.3±0.3	1.5	_	7.0			
		5.0±0.5	1.0	_	6.0			
Output disable time	t <sub>HZ</sub>	1.8±0.15	1.0	_	20.0	ns	G	Q
	t <sub>LZ</sub>	2.5±0.2	1.0	_	10.5			
		2.7	1.0	_	8.0			
		3.3±0.3	1.5	_	7.0			
		5.0±0.5	1.0	_	6.0			
Setup time	t <sub>su</sub>	1.8±0.15	6.0	_	_	ns		
		2.5±0.2	4.0	_	_			
		2.7	2.0	_	_			
		3.3±0.3	2.0	_	_			
		5.0±0.5	2.0	_	_			
Hold time	t <sub>h</sub>	1.8±0.15	4.0	_	_	ns		
		2.5±0.2	2.0	_	_			
		2.7	1.5	_	_			
		3.3±0.3	1.5	_	_			
		5.0±0.5	1.5	_	_			
Pulse width	tw	1.8±0.15	9.0	_	_	ns		
		2.5±0.2	4.0	_	_			
		2.7	3.3	_	_			
		3.3±0.3	3.3	_	_			
		5.0±0.5	3.3	_				
Between output	t <sub>OSLH</sub>	1.8±0.15	_	_	_	ns		1
pins skew <sup>*1</sup>	t <sub>OSHL</sub>	2.5±0.2	_	_	_	1		
		2.7	_		—	1		
		3.3±0.3		_	1.0			
		5.0±0.5	_		1.0	1		
Input capacitance	CIN	3.3	_	4.0	_	pF		1
Output capacitance	Co	3.3	_	8.0	_	pF		

Note: 1. This parameter is characterized but not tested.

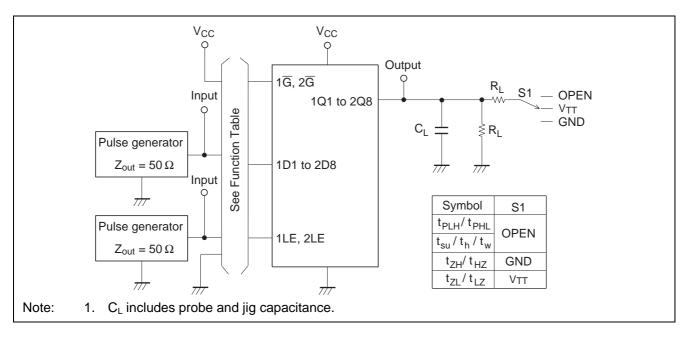
 $\text{tos}_{\text{LH}} = \mid t_{\text{PLHm}} \text{-} t_{\text{PLHn}} |, \text{tos}_{\text{HL}} = \mid t_{\text{PHLm}} \text{-} t_{\text{PHLn}} |$ 



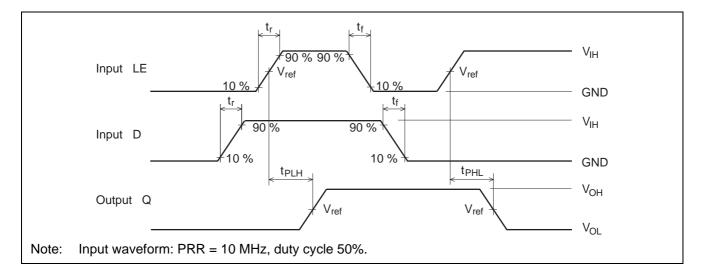
### **Operating Characteristics**

				Ta = 25°C			
Item	Symbol	V <sub>cc</sub> (V)	Min	Тур	Max	Unit	Test Conditions
Power dissipation	C <sub>PD</sub>	1.8	_	27		pF	f = 10 MHz
capacitance		2.5		28	_		
		3.3	_	30			
		5.0		35		1	

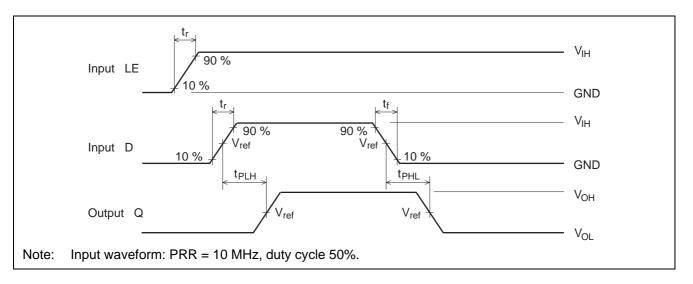
## **Test Circuit**



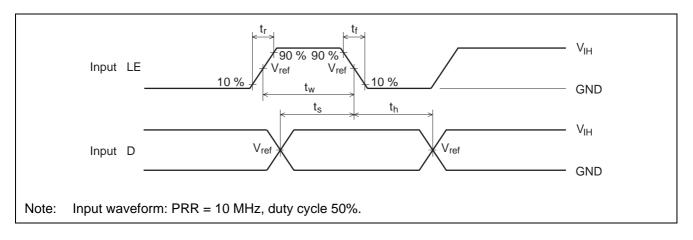
#### Waveforms – 1



#### Waveforms – 2



#### Waveforms - 3





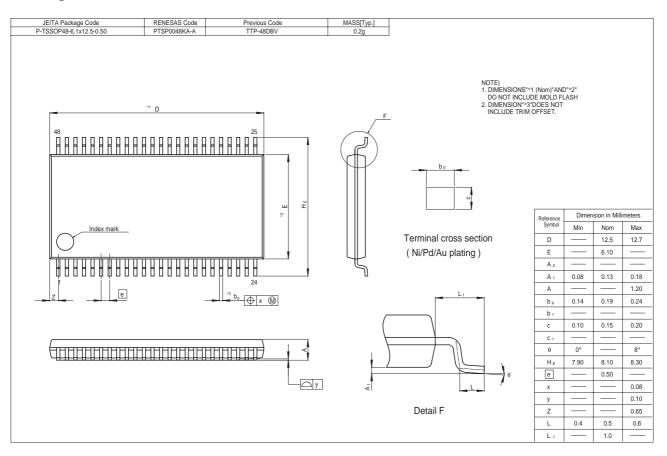
#### Waveforms – 4

Input G V	ref			<sup>7</sup> 90 % √ V <sub>ref</sub> 10 %			— V <sub>IH</sub> — GND
Waveform - A	<t< th=""><th>ZL V<sub>ref</sub></th><th></th><th>&lt; t<sub>LZ</sub></th><th>V<sub>OL</sub></th><th>+ ΔV</th><th>— ≈1/2 V — V<sub>OL</sub></th></t<>	ZL V <sub>ref</sub>		< t <sub>LZ</sub>	V <sub>OL</sub>	+ ΔV	— ≈1/2 V — V <sub>OL</sub>
Waveform - B	<	Vref		k		- ΔV	— V <sub>OH</sub> — ≈GND
	INPUTS	+ /+.	Vrof	\/ <del>~~</del>	C.	D.	43.4
V <sub>CC</sub> (V)	VIH	t <sub>r</sub> /t <sub>f</sub>	Vref			R <sub>L</sub>	ΔV
$V_{CC} = 1.8 \pm 0.15 \text{ V}$	V <sub>IH</sub> V <sub>CC</sub>	≤ 2 ns	1/2 V <sub>CC</sub>	2×V <sub>CC</sub>	30 pF	1.0 kΩ	0.15 V
V <sub>CC</sub> = 1.8±0.15 V V <sub>CC</sub> = 2.5±0.2 V	V <sub>IH</sub> V <sub>CC</sub> V <sub>CC</sub>	≤ 2 ns ≤ 2 ns	1/2 V <sub>CC</sub> 1/2 V <sub>CC</sub>	2× V <sub>CC</sub> 2× V <sub>CC</sub>	30 pF 30 pF	1.0 kΩ 500 Ω	0.15 V 0.15 V
V <sub>CC</sub> = 1.8±0.15 V V <sub>CC</sub> = 2.5±0.2 V V <sub>CC</sub> = 2.7 V	V <sub>IH</sub> V <sub>CC</sub> V <sub>CC</sub> 2.7 V	$\leq 2 \text{ ns}$ $\leq 2 \text{ ns}$ $\leq 2.5 \text{ ns}$	1/2 V <sub>CC</sub> 1/2 V <sub>CC</sub> 1.5 V	2× V <sub>CC</sub> 2× V <sub>CC</sub> 6 V	30 pF 30 pF 50 pF	1.0 kΩ 500 Ω 500 Ω	0.15 V 0.15 V 0.3 V
V <sub>CC</sub> = 1.8±0.15 V V <sub>CC</sub> = 2.5±0.2 V	V <sub>IH</sub> V <sub>CC</sub> V <sub>CC</sub>	≤ 2 ns ≤ 2 ns	1/2 V <sub>CC</sub> 1/2 V <sub>CC</sub>	2× V <sub>CC</sub> 2× V <sub>CC</sub>	30 pF 30 pF	1.0 kΩ 500 Ω	0.15 V 0.15 V

Notes: 1. Input waveform :PRR = 10 MHz, duty cycle 50%

- 2. Waveform A shows input conditions such that the output is "L" level when enable by the output control.
- 3. Waveform B shows input conditions such that the output is "H" level when enable by the output control.

### **Package Dimensions**





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